### Triple Channel PWM Controller with Integrated Driver for IMVP8 Mobile CPU Core Power Supply

### **General Description**

The RT3602AC is an IMVP8 compliant CPU power controller which includes three voltage rails : a 2/1 phase synchronous Buck controller, the MAIN VR, a single phase synchronous Buck controller, the auxiliary VR, and a single phase synchronous Buck controller, the VCCSA VR. The RT3602AC adopts G-NAVP<sup>TM</sup> (Green Native AVP) which is Richtek's proprietary topology derived from finite DC gain of EA amplifier with current mode control, making it easy to set the droop to meet all Intel CPU requirements of AVP (Adaptive Voltage Positioning). Based on the G-NAVP<sup>™</sup> topology, the RT3602AC also features a quick response mechanism for optimized AVP performance during load transient. The RT3602AC supports mode transition function with various operating states. A serial VID (SVID) interface is built in the RT3602AC to communicate with Intel IMVP8 compliant CPU. The RT3602AC supports VID on-the-fly function with three different slew rates : Fast, Slow and Decay. By utilizing the G-NAVP<sup>TM</sup> topology, the operating frequency of the RT3602AC varies with VID, load and input voltage to further enhance the efficiency even in CCM. Moreover, the G-NAVP<sup>™</sup> with CCRCOT (Constant Current Ripple COT) technology provides superior output voltage ripple over the entire input/output range. The built-in high accuracy DAC converts the SVID code ranging from 0.25V to 1.52V with 5mV per step. The RT3602AC integrates a high accuracy ADC for platform setting functions, such as quick response trigger level. Besides, the setting function also supposes this two rails address exchange. The RT3602AC provides VR ready output signals. It also features complete fault protection functions including over-voltage (OV), negative voltage (NV), over-current (OC) and under-voltage lockout (UVLO). The RT3602AC is available in the WQFN-52L 6x6 small foot print package.

#### Features

- Intel IMVP8 Serial VID Interface Compatible Power Management States
- 2/1 Phase (MAIN VR) + Single Phase (Auxiliary VR) + Single Phase (VCCSA VR) PWM Controller
- 1 Embedded MOSFET Driver at the MAIN VR, 1 Embedded MOSFET Driver at the Auxiliary VR, and Embedded MOSFET Driver at the VCCSA VR
- G-NAVP<sup>™</sup> (Green Native Adaptive Voltage Positioning) Topology
- 0.5% DAC Accuracy
- Differential Remote Voltage Sensing
- Built-in ADC for Platform Programming
- Accurate Current Balance
- System Thermal Compensated AVP
- Diode Emulation Mode at Light Load Condition for Multiple or Single Phase Operation
- Fast Transient Response
- VR Ready Indicator
- Thermal Throttling
- Current Monitor Output
- OVP, OCP, NVP, UVLO
- Slew Rate Setting/Address Flip Function
- DVID Enhancement

#### Applications

- IMVP8 Intel Core Supply
- Notebook/Desktop Computer/Servers Multi-Phase CPU
  Core Supply
- AVP Step-Down Converter

### **Simplified Application Circuit**





#### **Ordering Information Pin Configuration** (TOP VIEW) RT3602AC VREF06/PSET Package Type RGND MAIN VSEN\_MAIN PWM\_MAIN ISENN\_SA READ SA S, 's SA QW : WQFN-52L 6x6 (W-Type) ISENP RGND COMP SA NOM PSYS Lead Plating System Ŕ Ш Ш G : Green (Halogen Free and Pb Free) 52 51 41 40 Note : IMON\_MAIN DRVEN Richtek products are : 1 SET1 VCLK • RoHS compliant and compatible with the current require-ALERT FB\_MAIN COMP\_MAIN VDIO ments of IPC/JEDEC J-STD-020. VR\_HOT SET2 5 • Suitable for use in SnPb or Pb-free soldering processes. IMON\_AUXI SET3 6 ISENP\_AUXI ISEN1N\_MAIN GND 7 **ISENN\_AUXI** ISEN2N\_MAIN 8 **Marking Information** ISEN2P\_MAIN ISEN1P\_MAIN VSEN\_AUXI COMP\_AUXI 10 53 RT3602ACGQW : Product Number RGND\_AUXI TSEN\_MAIN 11 VIN 12 FB AUXI RT3602AC 28 YMDNN : Date Code VCC 13 TSEN AUXI 27 GQW 14 15 16 17 YMDNN BOOT\_MAIN LGATE\_AUXI BOOT\_SA UGATE\_SA PHASE\_SA LGATE\_SA PVCC .GATE\_MAIN PHASE MAIN JGATE\_MAIN PHASE\_AUXI BOOT\_AUXI JGATE

WQFN-52L 6x6

#### **Functional Pin Description**

Pin No	Pin Name	Pin Function
1	IMON_MAIN	MAIN rail VR current monitor output. This pin outputs a voltage proportional to the output current.
2	SET1	Platform setting. Platform can use this pin to set switching frequency, ki gain, QRTH, QR width and anti-overshoot for Auxiliary VR. Connect the SET1 pin to 5V and turn-on the EN pin, if the soldering is good, $V_{SEN\_MAIN} = V_{SEN\_AUXI} = 1.1V$ and $V_{SEN\_SA} = 1.05V$ .
3	FB_MAIN	Negative Input of the error amplifier. This pin is for MAIN rail VR output voltage feedback to controller.
4	COMP_MAIN	MAIN rail VR compensation. This pin is error amplifier output pin.
5	SET2	Platform setting. Platform can use this pin to set switching frequency, ki gain, QRTH, QR width and anti-overshoot for MAIN VR.
6	SET3	Platform setting. Platform can use this pin to set switching frequency, ki gain zero load-line, QRTH and QR width for VCCSA rail. And it can be set DVID TH and force-non-zero VBOOT function for MAIN and AUXI rail.
7, 8	ISEN[1:2]N_MAIN	Negative current sense inputs of multi-phase MAIN rail VR Channel 1 and 2.
10, 9	ISEN[1:2]P_MAIN	Positive current sense inputs of multi-phase MAIN rail VR Channel 1 and 2.
11	TSEN_MAIN	Thermal sense input for MAIN rail VR.
12	VIN	VIN input pin. Connect a low pass filter to this pin to set on-time.
13	VCC	Controller power supply. Connect this pin to 5V and place a decoupling capacitor $2.2\mu$ F at least. The decoupling capacitor is as close PWM controller as possible.

Pin No	Pin Name	Pin Function
14	BOOT_SA	Bootstrap supply for high-side gate MOSFET driver for VCCSA VR.
15	UGATE_SA	High-side driver output for VCCSA VR. Connect the pin to the gate of high-side MOSFET.
16	PHASE_SA	Switch node of high-side driver for VCCSA VR. Connect the pin to high-side MOSFE source together with the low-side MOSFET drain and inductor.
17	LGATE_SA	Low-side driver output for VCCSA VR. This pin drives the gate of low-side MOSFET.
18	PVCC	Driver power supply input. Connect this pin to GND by a minimum 2.2µF ceramic Capacitor.
19	LGATE_MAIN	Low-side driver output for MAIN rail VR. This pin drives the gate of low-side MOSFET.
20	PHASE_MAIN	Switch node of high-side driver for MAIN rail VR. Connect the pin to high-side MOSFE source together with the low-side MOSFET drain and inductor.
21	UGATE_MAIN	High-side driver output for MAIN rail VR. Connect the pin to the gate of high- side MOSFET.
22	BOOT_MAIN	Bootstrap supply for high-side gate MOSFET driver for MAIN rail VR.
23	LGATE_AUXI	Low-side driver output for auxiliary rail VR. This pin drives the gate of low- side MOSFET.
24	PHASE_AUXI	Switch node of high-side driver for auxiliary rail VR. Connect the pin to high- side MOSFE source together with the low-side MOSFET drain and inductor.
25	UGATE_AUXI	High-side driver output for auxiliary rail VR. Connect the pin to the gate of high-side MOSFET.
26	BOOT_AUXI	Bootstrap supply for high-side gate MOSFET driver for auxiliary rail VR.
27	TSEN_AUXI	Thermal sense input for VR.
28	FB_AUXI	Negative input of the error amplifier. This pin is for auxiliary rail VR output voltage feedback to controller.
29	RGND_AUXI	Return ground for auxiliary rail VR. This pin is the negative node of the differential remote voltage sensing.
30	COMP_AUXI	Auxiliary rail VR compensation. This pin is error amplifier output pin.
31	VSEN_AUXI	AUXI VR voltage sense input. This pin is connected to the terminal of AUXI VR output voltage.
32	ISENN_AUXI	Negative current sense input of single-phase AUXI rail.
33	ISENP_AUXI	Positive current sense input of single-phase AUXI rail.
34	IMON_AUXI	Auxiliary rail VR current monitor output. This pin outputs a voltage proportional to the output current.
35	VR_HOT	Thermal monitor output, this pin is active low.
36	VDIO	VR and CPU data transmission interface.
37	ALERT	SVID alert. (Active low)
38	VCLK	Synchronous clock from the CPU.
39	DRVEN	External driver enable control. Connecting to driver enable pin.
40	PWM_MAIN	PWM outputs for MAIN VR.
41	EN	VR enable control input.
42	VR_READY	VR ready indicator.



Pin No	Pin Name	Pin Function					
43	IMON_SA	VCCSA rail VR current monitor output. This pin outputs a voltage proportional to the output current.					
44	ISENP_SA	Positive current sense input of single-phase VCCSA rail VR.					
45	ISENN_SA	Negative current sense input of single-phase VCCSA rail VR.					
46	VREF06/PSET	Fixed 0.6V output reference voltage. This voltage is used to offset the output voltage of IMON pin. Between this pin and GND must be placed a exact $0.47 \mu F$ decoupling capacitor and $3.9 \Omega$ resistor.					
47	COMP_SA	VCCSA rail VR compensation. This pin is error amplifier output pin.					
48	RGND_SA	Return ground for VCCSA rail VR. This pin is the negative node of the differential remote voltage sensing.					
49	FB_SA	Negative input of the error amplifier. This pin is for VCCSA rail VR output voltage feedback to controller.					
50	PSYS	System input power monitor. Place the PSYS resistor as close to the IC as possible.					
51	VSEN_MAIN	MAIN VR voltage sense input. This pin is connected to the terminal of MAIN VR output voltage.					
52	RGND_MAIN	Return ground for MAIN rail VR. This pin is the negative node of the differential remote voltage sensing.					
53 (Exposed Pad)	GND	Ground. The exposed pad must be soldered to a large PCB and connected to GND for maximum power dissipation.					

### **Functional Block Diagram**





### Operation

The RT3602AC adopts G-NAVP<sup>TM</sup> (Green Native AVP) which is Richtek's proprietary topology derived from finite DC gain of EA amplifier with current mode control, making it easy to set the droop to meet all Intel CPU requirements of AVP (Adaptive Voltage Positioning).

The G-NAVP<sup>TM</sup> controller is one type of current mode constant on-time control with DC offset cancellation. The approach can not only improve DC offset problem for increasing system accuracy but also provide fast transient response. When current feedback signal reaches COMP signal, the RT3602AC generates an on-time width to achieve PWM modulation.

#### **TON GEN/Driver Interface PWMx**

Generate the sequentially according to the phase control signal from the Loop Control/Protection Logic. Pulse width is determined by current balance result and pin setting. Once quick response mechanism is triggered, VR will allow all PWM to turn on at the same time. PWM status is also controlled by Protection Logic. Different protections may cause different PWM status (Both High-Z or LG turn-on).

## SVID Interface/Configuration Registers/Control Logic

The interface receives the SVID signal from CPU and sends the relative signals to Loop Control/Protection Logic for loop control to execute the action by CPU. The registers save the pin setting data from ADC output. The Control Logic controls the ADC timing, generates the digital code of the VID for VSEN voltage.

#### Loop Control/Protection Logic

It controls the power on sequence, the protection behavior, and the operational phase number.

#### MUX and ADC

The MUX supports the inputs from SET1, SET2, SET3, IMON\_MAIN, IMON\_AUXI, TSEN\_MAIN and TSEN\_AUXI. The ADC converts these analog signals to digital codes for reporting or performance adjustment.

#### **Current Balance**

Each phase current sense signal is sent to the current balance circuit which adjusts the on-time of each phase to optimize current sharing.

#### **Offset Cancellation**

Cancel the current/voltage ripple issue to get the accurate VSEN.

#### UVLO

Detect the VCC voltage and issue POR signal as they are high enough.

#### DAC

Generate an analog signal according to the digital code generated by Control Logic.

Soft-Start & Slew Rate Control

Control the Dynamic VID slew rate of VSEN according to the SetVID fast or SetVID slow.

#### **Error Amp**

Error amplifier generates COMP\_MAIN/COMP\_AUXI/ COMP\_SA signal by the difference between output of MAIN/Auxiliary/SA rail and FB\_MAIN/FB\_AUXI/FB\_SA.

#### **PWM CMP**

The PWM comparator compares COMP signal and current feedback signal to generate a signal for TON trigger.

#### **IMON Filter**

IMON Filter is used for average sum current signal by analog RC filter.

Table 1. IMVP8 VID Code Table									
VID7	VID6	VID5	VID4	VID3	VID2	VID1	VID0	HEX	Voltage (V)
0	0	0	0	0	0	0	1	01	0.25
0	0	0	0	0	0	1	0	02	0.255
0	0	0	0	0	0	1	1	03	0.26
0	0	0	0	0	1	0	0	04	0.265
0	0	0	0	0	1	0	1	05	0.27
0	0	0	0	0	1	1	0	06	0.275
0	0	0	0	0	1	1	1	07	0.28
0	0	0	0	1	0	0	0	08	0.285
0	0	0	0	1	0	0	1	09	0.29
0	0	0	0	1	0	1	0	0A	0.295
0	0	0	0	1	0	1	1	0B	0.3
0	0	0	0	1	1	0	0	0C	0.305
0	0	0	0	1	1	0	1	0D	0.31
0	0	0	0	1	1	1	0	0E	0.315
0	0	0	0	1	1	1	1	0F	0.32
0	0	0	1	0	0	0	0	10	0.325
0	0	0	1	0	0	0	1	11	0.33
0	0	0	1	0	0	1	0	12	0.335
0	0	0	1	0	0	1	1	13	0.34
0	0	0	1	0	1	0	0	14	0.345
0	0	0	1	0	1	0	1	15	0.35
0	0	0	1	0	1	1	0	16	0.355
0	0	0	1	0	1	1	1	17	0.36
0	0	0	1	1	0	0	0	18	0.365
0	0	0	1	1	0	0	1	19	0.37
0	0	0	1	1	0	1	0	1A	0.375
0	0	0	1	1	0	1	1	1B	0.38
0	0	0	1	1	1	0	0	1C	0.385
0	0	0	1	1	1	0	1	1D	0.39
0	0	0	1	1	1	1	0	1E	0.395
0	0	0	1	1	1	1	1	1F	0.4
0	0	1	0	0	0	0	0	20	0.405
0	0	1	0	0	0	0	1	21	0.41
0	0	1	0	0	0	1	0	22	0.415
0	0	1	0	0	0	1	1	23	0.42
0	0	1	0	0	1	0	0	24	0.425

Table 1. IMVP8 VID Code Table



VID7	VID6	VID5	VID4	VID3	VID2	VID1	VID0	HEX	Voltage (V)
0	0	1	0	0	1	0	1	25	0.43
0	0	1	0	0	1	1	0	26	0.435
0	0	1	0	0	1	1	1	27	0.44
0	0	1	0	1	0	0	0	28	0.445
0	0	1	0	1	0	0	1	29	0.45
0	0	1	0	1	0	1	0	2A	0.455
0	0	1	0	1	0	1	1	2B	0.46
0	0	1	0	1	1	0	0	2C	0.465
0	0	1	0	1	1	0	1	2D	0.47
0	0	1	0	1	1	1	0	2E	0.475
0	0	1	0	1	1	1	1	2F	0.48
0	0	1	1	0	0	0	0	30	0.485
0	0	1	1	0	0	0	1	31	0.49
0	0	1	1	0	0	1	0	32	0.495
0	0	1	1	0	0	1	1	33	0.5
0	0	1	1	0	1	0	0	34	0.505
0	0	1	1	0	1	0	1	35	0.51
0	0	1	1	0	1	1	0	36	0.515
0	0	1	1	0	1	1	1	37	0.52
0	0	1	1	1	0	0	0	38	0.525
0	0	1	1	1	0	0	1	39	0.53
0	0	1	1	1	0	1	0	3A	0.535
0	0	1	1	1	0	1	1	3B	0.54
0	0	1	1	1	1	0	0	3C	0.545
0	0	1	1	1	1	0	1	3D	0.55
0	0	1	1	1	1	1	0	3E	0.555
0	0	1	1	1	1	1	1	3F	0.56
0	1	0	0	0	0	0	0	40	0.565
0	1	0	0	0	0	0	1	41	0.57
0	1	0	0	0	0	1	0	42	0.575
0	1	0	0	0	0	1	1	43	0.58
0	1	0	0	0	1	0	0	44	0.585
0	1	0	0	0	1	0	1	45	0.59
0	1	0	0	0	1	1	0	46	0.595
0	1	0	0	0	1	1	1	47	0.6
0	1	0	0	1	0	0	0	48	0.605
0	1	0	0	1	0	0	1	49	0.61

### **RT3602AC**

VID7	VID6	VID5	VID4	VID3	VID2	VID1	VID0	HEX	Voltage (V)
0	1	0	0	1	0	1	0	4A	0.615
0	1	0	0	1	0	1	1	4B	0.62
0	1	0	0	1	1	0	0	4C	0.625
0	1	0	0	1	1	0	1	4D	0.63
0	1	0	0	1	1	1	0	4E	0.635
0	1	0	0	1	1	1	1	4F	0.64
0	1	0	1	0	0	0	0	50	0.645
0	1	0	1	0	0	0	1	51	0.65
0	1	0	1	0	0	1	0	52	0.655
0	1	0	1	0	0	1	1	53	0.66
0	1	0	1	0	1	0	0	54	0.665
0	1	0	1	0	1	0	1	55	0.67
0	1	0	1	0	1	1	0	56	0.675
0	1	0	1	0	1	1	1	57	0.68
0	1	0	1	1	0	0	0	58	0.685
0	1	0	1	1	0	0	1	59	0.69
0	1	0	1	1	0	1	0	5A	0.695
0	1	0	1	1	0	1	1	5B	0.7
0	1	0	1	1	1	0	0	5C	0.705
0	1	0	1	1	1	0	1	5D	0.71
0	1	0	1	1	1	1	0	5E	0.715
0	1	0	1	1	1	1	1	5F	0.72
0	1	1	0	0	0	0	0	60	0.725
0	1	1	0	0	0	0	1	61	0.73
0	1	1	0	0	0	1	0	62	0.735
0	1	1	0	0	0	1	1	63	0.74
0	1	1	0	0	1	0	0	64	0.745
0	1	1	0	0	1	0	1	65	0.75
0	1	1	0	0	1	1	0	66	0.755
0	1	1	0	0	1	1	1	67	0.76
0	1	1	0	1	0	0	0	68	0.765
0	1	1	0	1	0	0	1	69	0.77
0	1	1	0	1	0	1	0	6A	0.775
0	1	1	0	1	0	1	1	6B	0.78
0	1	1	0	1	1	0	0	6C	0.785
0	1	1	0	1	1	0	1	6D	0.79
0	1	1	0	1	1	1	0	6E	0.795



VID7	VID6	VID5	VID4	VID3	VID2	VID1	VID0	HEX	Voltage (V)
0	1	1	0	1	1	1	1	6F	0.8
0	1	1	1	0	0	0	0	70	0.805
0	1	1	1	0	0	0	1	71	0.81
0	1	1	1	0	0	1	0	72	0.815
0	1	1	1	0	0	1	1	73	0.82
0	1	1	1	0	1	0	0	74	0.825
0	1	1	1	0	1	0	1	75	0.83
0	1	1	1	0	1	1	0	76	0.835
0	1	1	1	0	1	1	1	77	0.84
0	1	1	1	1	0	0	0	78	0.845
0	1	1	1	1	0	0	1	79	0.85
0	1	1	1	1	0	1	0	7A	0.855
0	1	1	1	1	0	1	1	7B	0.86
0	1	1	1	1	1	0	0	7C	0.865
0	1	1	1	1	1	0	1	7D	0.87
0	1	1	1	1	1	1	0	7E	0.875
0	1	1	1	1	1	1	1	7F	0.88
1	0	0	0	0	0	0	0	80	0.885
1	0	0	0	0	0	0	1	81	0.89
1	0	0	0	0	0	1	0	82	0.895
1	0	0	0	0	0	1	1	83	0.9
1	0	0	0	0	1	0	0	84	0.905
1	0	0	0	0	1	0	1	85	0.91
1	0	0	0	0	1	1	0	86	0.915
1	0	0	0	0	1	1	1	87	0.92
1	0	0	0	1	0	0	0	88	0.925
1	0	0	0	1	0	0	1	89	0.93
1	0	0	0	1	0	1	0	8A	0.935
1	0	0	0	1	0	1	1	8B	0.94
1	0	0	0	1	1	0	0	8C	0.945
1	0	0	0	1	1	0	1	8D	0.95
1	0	0	0	1	1	1	0	8E	0.955
1	0	0	0	1	1	1	1	8F	0.96
1	0	0	1	0	0	0	0	90	0.965
1	0	0	1	0	0	0	1	91	0.97
1	0	0	1	0	0	1	0	92	0.975
1	0	0	1	0	0	1	1	93	0.98

### **RT3602AC**

VID7	VID6	VID5	VID4	VID3	VID2	VID1	VID0	HEX	Voltage (V)
1	0	0	1	0	1	0	0	94	0.985
1	0	0	1	0	1	0	1	95	0.99
1	0	0	1	0	1	1	0	96	0.995
1	0	0	1	0	1	1	1	97	1
1	0	0	1	1	0	0	0	98	1.005
1	0	0	1	1	0	0	1	99	1.01
1	0	0	1	1	0	1	0	9A	1.015
1	0	0	1	1	0	1	1	9B	1.02
1	0	0	1	1	1	0	0	9C	1.025
1	0	0	1	1	1	0	1	9D	1.03
1	0	0	1	1	1	1	0	9E	1.035
1	0	0	1	1	1	1	1	9F	1.04
1	0	1	0	0	0	0	0	A0	1.045
1	0	1	0	0	0	0	1	A1	1.05
1	0	1	0	0	0	1	0	A2	1.055
1	0	1	0	0	0	1	1	A3	1.06
1	0	1	0	0	1	0	0	A4	1.065
1	0	1	0	0	1	0	1	A5	1.07
1	0	1	0	0	1	1	0	A6	1.075
1	0	1	0	0	1	1	1	A7	1.08
1	0	1	0	1	0	0	0	A8	1.085
1	0	1	0	1	0	0	1	A9	1.09
1	0	1	0	1	0	1	0	AA	1.095
1	0	1	0	1	0	1	1	AB	1.1
1	0	1	0	1	1	0	0	AC	1.105
1	0	1	0	1	1	0	1	AD	1.11
1	0	1	0	1	1	1	0	AE	1.115
1	0	1	0	1	1	1	1	AF	1.12
1	0	1	1	0	0	0	0	B0	1.125
1	0	1	1	0	0	0	1	B1	1.13
1	0	1	1	0	0	1	0	B2	1.135
1	0	1	1	0	0	1	1	B3	1.14
1	0	1	1	0	1	0	0	B4	1.145
1	0	1	1	0	1	0	1	B5	1.15
1	0	1	1	0	1	1	0	B6	1.155
1	0	1	1	0	1	1	1	B7	1.16
1	0	1	1	1	0	0	0	B8	1.165



VID7	VID6	VID5	VID4	VID3	VID2	VID1	VID0	HEX	Voltage (V)
1	0	1	1	1	0	0	1	B9	1.17
1	0	1	1	1	0	1	0	BA	1.175
1	0	1	1	1	0	1	1	BB	1.18
1	0	1	1	1	1	0	0	BC	1.185
1	0	1	1	1	1	0	1	BD	1.19
1	0	1	1	1	1	1	0	BE	1.195
1	0	1	1	1	1	1	1	BF	1.2
1	1	0	0	0	0	0	0	C0	1.205
1	1	0	0	0	0	0	1	C1	1.21
1	1	0	0	0	0	1	0	C2	1.215
1	1	0	0	0	0	1	1	C3	1.22
1	1	0	0	0	1	0	0	C4	1.225
1	1	0	0	0	1	0	1	C5	1.23
1	1	0	0	0	1	1	0	C6	1.235
1	1	0	0	0	1	1	1	C7	1.24
1	1	0	0	1	0	0	0	C8	1.245
1	1	0	0	1	0	0	1	C9	1.25
1	1	0	0	1	0	1	0	CA	1.255
1	1	0	0	1	0	1	1	СВ	1.26
1	1	0	0	1	1	0	0	СС	1.265
1	1	0	0	1	1	0	1	CD	1.27
1	1	0	0	1	1	1	0	CE	1.275
1	1	0	0	1	1	1	1	CF	1.28
1	1	0	1	0	0	0	0	D0	1.285
1	1	0	1	0	0	0	1	D1	1.29
1	1	0	1	0	0	1	0	D2	1.295
1	1	0	1	0	0	1	1	D3	1.3
1	1	0	1	0	1	0	0	D4	1.305
1	1	0	1	0	1	0	1	D5	1.31
1	1	0	1	0	1	1	0	D6	1.315
1	1	0	1	0	1	1	1	D7	1.32
1	1	0	1	1	0	0	0	D8	1.325
1	1	0	1	1	0	0	1	D9	1.33
1	1	0	1	1	0	1	0	DA	1.335
1	1	0	1	1	0	1	1	DB	1.34
1	1	0	1	1	1	0	0	DC	1.345
1	1	0	1	1	1	0	1	DD	1.35

### **RT3602AC**

VID7	VID6	VID5	VID4	VID3	VID2	VID1	VID0	HEX	Voltage (V)
1	1	0	1	1	1	1	0	DE	1.355
1	1	0	1	1	1	1	1	DF	1.36
1	1	1	0	0	0	0	0	E0	1.365
1	1	1	0	0	0	0	1	E1	1.37
1	1	1	0	0	0	1	0	E2	1.375
1	1	1	0	0	0	1	1	E3	1.38
1	1	1	0	0	1	0	0	E4	1.385
1	1	1	0	0	1	0	1	E5	1.39
1	1	1	0	0	1	1	0	E6	1.395
1	1	1	0	0	1	1	1	E7	1.4
1	1	1	0	1	0	0	0	E8	1.405
1	1	1	0	1	0	0	1	E9	1.41
1	1	1	0	1	0	1	0	EA	1.415
1	1	1	0	1	0	1	1	EB	1.42
1	1	1	0	1	1	0	0	EC	1.425
1	1	1	0	1	1	0	1	ED	1.43
1	1	1	0	1	1	1	0	EE	1.435
1	1	1	0	1	1	1	1	EF	1.44
1	1	1	1	0	0	0	0	F0	1.445
1	1	1	1	0	0	0	1	F1	1.45
1	1	1	1	0	0	1	0	F2	1.455
1	1	1	1	0	0	1	1	F3	1.46
1	1	1	1	0	1	0	0	F4	1.465
1	1	1	1	0	1	0	1	F5	1.47
1	1	1	1	0	1	1	0	F6	1.475
1	1	1	1	0	1	1	1	F7	1.48
1	1	1	1	1	0	0	0	F8	1.485
1	1	1	1	1	0	0	1	F9	1.49
1	1	1	1	1	0	1	0	FA	1.495
1	1	1	1	1	0	1	1	FB	1.5
1	1	1	1	1	1	0	0	FC	1.505
1	1	1	1	1	1	0	1	FD	1.51
1	1	1	1	1	1	1	0	FE	1.515
1	1	1	1	1	1	1	1	FF	1.52



### Absolute Maximum Ratings (Note 1)

VCC to GND	
RGND to GND	
• VIN to GND	
PVCC to GND	
BOOT to PHASE	0.3V to 6.5V
PHASE to GND	
DC	–0.3V to 30V
<20ns	–10V to 35V
LGATE to GND	
DC	0.3V to (VCC+ 0.3V)
<20ns	2V to (VCC+ 0.3V)
UGATE to GND	
DC	(V <sub>PHASE</sub> – 0.3V) to (V <sub>BOOT</sub> + 0.3V)
<20ns	(V <sub>PHASE</sub> – 2V) to (V <sub>BOOT</sub> + 0.3V)
Other Pins	
• Power Dissipation, $P_D @ T_A = 25^{\circ}C$	
WQFN-52L 6x6	3.77W
Package Thermal Resistance (Note 2)	
WQFN-52L 6x6, $\theta_{JA}$	26.5°C/W
WQFN-52L 6x6, $\theta_{JC}$	6.5°C/W
Junction Temperature	150°C
• Lead Temperature (Soldering, 10 sec.)	260°C
Storage Temperature Range	
ESD Susceptibility (Note 3)	
HBM (Human Body Model)	2kV

### Recommended Operating Conditions (Note 4)

Ambient Temperature Range	–40°C to 85°C
Junction Temperature Range	–40°C to 125°C
Supply Voltage, PVCC	4.5V to 5.5V
Supply Voltage, VCC	4.5V to 5.5V
Supply Voltage, VIN	4.5V to 24V

#### **Electrical Characteristics**

(V<sub>CC</sub> = 5V,  $T_A$  = 25°C, unless otherwise specified)

Parameter	Symbol	Test Conditions	Min	Тур	Мах	Unit		
Supply Input						•		
Supply Voltage	Vcc		4.5	5	5.5	V		
Supply Current	lvcc	V <sub>EN</sub> = 1.05V, no switching		9	15			
Supply Current at PS4	IVCC_PS4	V <sub>EN</sub> = 1.05V, no switching		0.2	0.25	mA		
Shutdown Current	ISHDN	V <sub>EN</sub> = 0V		10	20	μΑ		
Driver Supply Voltage	VPVCC		4.5		5.5	V		
Reference and DAC								
		VDAC = 0.75V - 1.52V	-0.5%	0	0.5%	% of VID		
DAC Accuracy	VFB	VDAC = 0.5V - 0.745V	-8	0	8	<u> </u>		
		VDAC = 0.25V - 0.495V	-10	0	10	- mV		
Slew Rate						•		
	0.5	Set VID fast	30	34	38			
Dynamic VID Slew Rate	SR	Set VID slow, set slow = 1/2 Fast	15	17	19	- mV/μs		
EA Amplifier						•		
DC Gain	ADC	R <sub>L</sub> = 47kΩ	70	80		dB		
Gain-Bandwidth Product	GBW	C <sub>LOAD</sub> = 5pF		5		MHz		
Input Offset	VEAOFS		-3		3	mV		
Slew Rate	SREA	$C_{LOAD}$ = 10pF (Gain= -4, R <sub>F</sub> = 47k $\Omega$ , V <sub>OUT</sub> =0.5V to -3V)		5		V/µs		
Output Voltage Range	VCOMP	R <sub>L</sub> = 47kΩ	0.3		3.6	V		
Max Source/Sink Current	IOUTEA	V <sub>COMP</sub> = 2V		5		mA		
Current Sensing Amplifi	er							
Input Offset Voltage	Voscs		-0.4		0.4	mV		
Impedance at Positive Input	RISENXP		1		-	MΩ		
Current Mirror Gain	Amirror	IIMON/ISEN×N	0.97	1	1.03	A/A		
Input Range	VISEN_IN	V <sub>DAC</sub> = 1.1V, I <sub>SENP_x</sub> – I <sub>SENN_x</sub>	-40		40	mV		
TON Setting								
On-Time Setting	ton	V <sub>IN</sub> = 10V, V <sub>DAC</sub> = 1V, f = 400k		250		ns		
Minimum Off-Time	toff	V <sub>DAC</sub> = 1		180	300	ns		
Protections						•		
Under-Voltage Lockout	VUVLO	Falling edge	3.9	4.1	4.2	V		
Threshold	$\Delta V_{UVLO}$	Rising edge hysteresis	100	170	250	mV		
Over-Voltage Protection	Vov			VID + 400	mV			
Threshold		Lower limit to 1V	1300	1350	1400	mV		



Parameter	Symbol	Test Conditions	Min	Тур	Мах	Unit		
Under-Voltage Protection			-400	-350	-300	mV		
Threshold	Vuv	Respect to VID voltage				mV		
Negative Voltage Protection Threshold	V <sub>NV</sub>		-100	-50		mV		
VRON and VR_READY								
	VIH	Respect to 1V, 70%	0.7			V		
VRON Threshold	VIL	Respect to 1V, 30%			0.3	V		
Leakage Current of VRON			-1		1	μA		
PGOOD Pull Low Voltage	Vpgood	I <sub>VR_Ready</sub> = 10mA			0.13	V		
Serial VID and VR_HOT								
	VIH	Respect to INTEL Spec. with 50mV	0.65					
VCLK, VDIO	VIL	hysteresis			0.45	V		
Leakage Current of	VIL .				0.10			
VCLK, VDIO, ALERT and VR_HOT	I <sub>LEAK_IN</sub>		-1		1	μA		
VDIO, ALERT and		I <sub>VDIO</sub> = 10mA			0.13	V		
VR_HOT Pull Low		IALERT = 10mA						
Voltage		I <sub>VR НОТ</sub> = 10mA						
VREF								
VREF06	VREF		0.595	0.6	0.605	V		
ADC								
	VIMON	$V_{IMON} - V_{IMON_INI} = 0.8V$ , MAIN rail, 2 phase application		255		– Decimal		
Digital IMON Set		$V_{IMON} - V_{IMON_INI} = 0.4V$ , single phase application		255				
Update Period	timon			125		μS		
TSEN Threshold for Tmp_Zone[7] Transition		100°C		1.092				
TSEN Threshold for Tmp_Zone[6] Transition		97°C		1.132				
TSEN Threshold for Tmp_Zone[5] Transition	VTSEN	94°C		1.176				
TSEN Threshold for Tmp_Zone[4] Transition		91°C		1.226		v		
TSEN Threshold for Tmp_Zone[3] Transition		88°C		1.283		v		
TSEN Threshold for Tmp_Zone[2] Transition		85°C		1.346		]		
TSEN Threshold for Tmp_Zone[1] Transition		82°C		1.418				
TSEN Threshold for Tmp_Zone[0] Transition		75°C		1.624				
	<b>t</b> TSEN			100		μs		

### **RT3602AC**

Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit		
Switching Timing								
UGATEx Rising Time	tUGATEr	3nF load		8		ns		
UGATEx Falling Time	tUGATEf	3nF load		8		ns		
LGATEx Rising Time	tLGATEr	3nF load		8		ns		
LGATEx Falling Time	<b>t</b> LGATEf	3nF load		4		ns		
	tUGATEpgh	Output unloaded		20				
Brongation Dolov	tUGATEpdl	Output unloaded		35		20		
Propagation Delay	tLGATEpdh	Output unloaded		20		ns		
	tLGATEpdI	Output unloaded		35				
Output		·						
UGATEx Drive Source	RUGATEsr	V <sub>BOOT</sub> – V <sub>PHASE</sub> = 5V, I <sub>Source</sub> = 100mA		1		Ω		
UGATEx Drive Sink	RUGATEsk	V <sub>BOOT</sub> – V <sub>PHASE</sub> = 5V, I <sub>Sink</sub> = 100mA		1		Ω		
LGATEx Drive Source	RLGATEsr	I <sub>Source</sub> = 100mA		1		Ω		
LGATEx Drive Sink	RLGATEsk	I <sub>Sink</sub> = 100mA		0.5		Ω		
ITSEN								
TSEN Source Current	I <sub>TSEN</sub>	V <sub>TSEN</sub> = 1.6V	79.2	80	80.8	μA		

- **Note 1.** Stresses beyond those listed "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions may affect device reliability.
- Note 2.  $\theta_{JA}$  is measured under natural convection (still air) at  $T_A = 25^{\circ}C$  with the component mounted on a high effectivethermal-conductivity four-layer test board on a JEDEC 51-7 thermal measurement standard.  $\theta_{JC}$  is measured at the exposed pad of the package.
- Note 3. Devices are ESD sensitive. Handling precaution is recommended.
- Note 4. The device is not guaranteed to function outside its operating conditions.



### **Typical Application Circuit**

#### For MAIN Two Phase Application



#### For MAIN Single Phase Application











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DS3602AC-01 June 2017















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### **RT3602AC**

#### **Applications information**

The RT3602AC includes three voltage rails : a 2/1 phase synchronous Buck controller, the MAIN VR, a single multiphase synchronous Buck controller, the auxiliary VR, and a single phase synchronous Buck controller, the VCCSA VR, designed to meet Intel IMVP8 compatible CPUs specification with a serial SVID control interface. The controller uses an ADC to implement all kinds of settings to save total pin number for easy use and increasing PCB space utilization. The RT3602AC is used in notebooks, desktop computers and servers.

#### **General loop Function**

#### G-NAVP<sup>™</sup> Control Mode

The RT3602AC adopts the G-NAVP<sup>™</sup> controller, which is a current mode constant on-time control with DC offset cancellation. The approach can not only improve DC offset problem for increasing system accuracy but also provide fast transient response. When current feedback signal reaches comp signal, the RT3602AC generates an ontime width to achieve PWM modulation. Figure 1 shows the basic G-NAVP<sup>™</sup> behavior waveforms in continuous conduct mode (CCM).



## Figure 1 (a). G-NAVP<sup>™</sup> Behavior Waveforms in CCM in Steady State



Figure 1 (b). G-NAVP<sup>™</sup> Behavior Waveforms in CCM in Load Transient.

#### **Diode Emulation Mode (DEM)**

As well-known, the dominate power loss is switching related loss during light load, hence VR needs to be operated in asynchronous mode (or called discontinuous conduct mode, DCM) to reduce switching related loss since switching frequency is dependent on loading in the asynchronous mode. The RT3602AC can operate in diode emulation mode (DEM) to improve light load efficiency. In DEM operation, the behavior of low-side MOSFET(s) needs to work like a diode, that is, the low-side MOSFET(s) will be turned on when the phase voltage is a negative value, i.e. the inductor current follows from Source to Drain of low-side MOSFET(s). And the low-side MOSFET(s) will be turned off when phase voltage is a positive value, i.e. reversed current is not allowed. Figure 2 shows the control behavior in DEM. Figure 3 shows the G-NAVP<sup>™</sup> operation in DEM to illustrate the control behaviors. When the load decreases, the discharge time of output capacitors increases during UGATE and LGATE are turned off. Hence, the switching frequency and switching loss will be reduced to improve efficiency in light load condition.





Figure 2. Diode Emulation Mode (DEM) in Steady State



Figure 3. (b)

Figure 3. G-NAVP<sup>™</sup> Operation in DEM. (a) : The load is lighter, output capacitor discharge slope is smaller and the switching frequency is lower. (b) : The load is increasing, output capacitor discharge slope is increased and switching frequency is increased, too.

#### **Phase Interleaving Function**

The RT3602AC is a multi-output controller, the MAIN rail of the RT3602AC has a phase interleaving function, 180 degree phase shift for 2-phase operation which can help reduce output voltage ripple and EMI problem.

#### **Multi-Function Pin Setting Mechanism**

For reducing total pin number of package, SET [1:3], TSEN\_Main and TSEN\_AUXI pins adopt the multi-function pin setting mechanism in the RT3602AC. Figure 4 illustrates this operating mechanism for SET [1:3]. The voltage at VREF pin will be pulled up to 3.2V after power ready (POR). First, external voltage divider is used to set the Function1, and then internal current source  $80\mu$ A is used to set the Function2. The setting voltage of Function1 and Function2 can be represented as

 $V_{Function1} = \frac{R2}{R1 + R2} \times 3.2V$  $V_{Function2} = 80 \mu A \times \frac{R1 \times R2}{R1 + R2}$ 

All function setting will be done within  $500\mu s$  after power ready (POR), and the voltage at VREF pin will be fixed to 0.6V after all function setting over.

If  $V_{\text{Function1}}$  and  $V_{\text{Function2}}$  are determined, R1 and R2 can be calculated as follows :

 $R1 = \frac{3.2V \times V_{Function2}}{80 \,\mu A \times V_{Function1}}$  $R2 = \frac{R1 \times V_{Function1}}{3.2V - V_{Function1}}$ 



# Figure 4. Multi-Function Pin Setting Mechanism for SET [1:3]

SETx

SR2

Function 1

Register

Function 2

Register

Connecting a R3 resistor from SETx pin or SETAx pin to the middle node of voltage divider can help to fine tune the set voltage of Function 2, which does not affect the set voltage of Function1. The Figure 5 shows the setting method and the set voltage of Function 1 and Function2 can be represented as :

 $V_{Function1} = \frac{R2}{R1 + R2} \times 3.2V$  $V_{Function2} = 80 \mu A \times \left(R3 + \frac{R1 \times R2}{R1 + R2}\right)$ 

### **RT3602AC**



Figure 5. Multi-Function Pin Setting Mechanism with a R3 Resistor to Fine Tune the Set Voltage of Function2

Figure 6 shows operating mechanism for TSEN\_Main and TSEN\_AUXI pins. There is only voltage divider Function to program VR. The internal current source is used to thermal sensing. The Function for program VR can be represented as



Figure 6. Multi-Function Pin Setting Mechanism for TSEN\_MAIN and TSEN\_AUXI By the way, Function1 of SET1 and SET2 pins are used to program QR threshold and QR width for MAIN and AUXI rails, respectively. Function1 of SET3 pin is used to setting force-non-zero VBOOT, SA rail TON factor, and SA rail DVID threshold. Function2 of SET1 and SET2 pins are used to program TON factor, Ki gain and anti-overshoot functions for MAIN and AUXI rails. Function2 of SET3 can be setting DVID threshold for MAIN and AUXI rails. TSEN\_AUXI pin is used to set ICCMAX and zero load-line for SA rail. TSEN\_MAIN is used to program ICCMAX of AUXI and SA rails. In addition, Richtek provide a Microsoft Excel-based spreadsheet to help design SETx, TSEN\_Main and TSEN\_AUXI resistor network.

#### TSEN\_Main, TSEN\_AUXI and VR\_HOT

The VR\_HOT signal is an open-drain signal which is used for VR thermal protection. When the sensed voltage in each TSEN pin is less than 1.092, the VR\_HOT signal will be pulled-low to notify CPU that the thermal protection needs to work. According to Intel VR definition, VR\_HOT signal needs acting if VR power chain temperature exceeds 100°C. Placing an NTC thermistor at the hottest area in the VR power chain and its connection is shown in Figure 7, to design the TSEN network so that V<sub>TSEN</sub> = 1.092V at 100°C. The resistance accuracy of TSEN network is recommended to be 1% or higher.

$$V_{TSEN_X} = 80 \mu A \times [(R_{NTC} //R3) + (R1 //R2)]$$



Figure 7. VR\_HOT Circuit

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#### Power Ready (POR) Detection

During start-up, the RT3602AC detects the voltage at the voltage input pins :  $V_{CC}$  and EN. When  $V_{CC}$ > 4.45V, the RT3602AC recognizes the power state of system to be ready (POR = high) and waits for enable command at the EN pin. After POR = high and  $V_{EN}$ > 0.7V, the RT3602AC enters start-up sequence. If  $V_{CC}$  drops below low threshold (POR = low), the RT3602AC enters power down sequence and all functions will be disabled. Normally, connecting system voltage  $V_{TT}$  (1.05V) to the EN pin is recommended. 2ms (max) after the chip has been enabled, the SVID circuitry will be ready. All the protection latches (OVP, OCP, UVP) will be cleared only by  $V_{CC}$ . The condition of VEN = low will not clear these latches. Figure 8 and Figure 9 show the POR detection and the timing chart for POR process, respectively.

#### Under-Voltage Lockout (UVLO)

During normal operation, if the voltage at the VCC pin drops below POR threshold 4.14V (min), the VR triggers UVLO. The UVLO protection forces all high-side MOSFETs and low-side MOSFETs off by shutting down internal PWM logic drivers.









#### Phase Disable (Before POR)

The number of active phases is determined by the internal circuitry that monitors the ISENxN voltages during startup. Normally, the MAIN rail operates as a 2-phase PWM controller. Pulling ISEN2N to VCC programs a 1-phase operation. Before POR, VR detects whether the voltage of ISEN2N is higher than "VCC – 1V" to decide how many phases should be active. Phase selection is only active during POR. When POR = high, the number of active phases is determined and latched. The unused ISENxP pins are recommended to be connected to VCC and unused PWM pins can be left floating.

#### Switching Frequency Setting

The RT3602AC is one kind of constant on-time control. The patented CCRCOT (Constant Current Ripple COT) technology can generate an adaptive on-time with input voltage and VID code to obtain a constant current ripple, so that the output voltage ripple can be controlled nearly like a constant as different input and output voltages change.

The Ton equation can be classified as below two regions.

$$\begin{split} V_{DAC} &\geq 0.9 \\ T_{ON} &= \frac{1.2 \mu \times V_{DAC}}{k_{TON} \times (V_{IN} - V_{DAC})} + 15n \end{split}$$

 $V_{DAC} < 0.9$  $T_{ON} = \frac{1.08\mu}{k_{TON} \times (V_{IN} - V_{DAC})} + 15n$ 

where  $k_{TON}$  is a coefficient which can be selected by SET[1 to 3] pins for each VR rail. Table 3 and Table 6 show the  $k_{TON}$  coefficient and ki gain setting for each VR rail on the SET[1 to 3] pins.

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		V <sub>REF</sub> × R1 x R2 R1+R2		QRTH_X (mV)	QRWIDTH_X (% of On-Time)
Min	Тур	Max	Unit		
24.77419	25.02444	25.27468	mV	-	160%
74.32258	75.07331	75.82405	mV	Disable	130%
123.871	125.1222	126.3734	mV	_	100%
173.4194	175.1711	176.9228	mV		70%
222.9677	225.2199	227.4721	mV		160%
272.5161	275.2688	278.0215	mV	- 10 -	130%
322.0645	325.3177	328.5709	mV		100%
371.6129	375.3666	379.1202	mV		70%
421.1613	425.4154	429.6696	mV		160%
470.7097	475.4643	480.219	mV	15	130%
520.2581	525.5132	530.7683	mV	- 15	100%
569.8065	575.5621	581.3177	mV		70%
619.3548	625.6109	631.8671	mV		160%
668.9032	675.6598	682.4164	mV		130%
718.4516	725.7087	732.9658	mV	- 20	100%
768	775.7576	783.5152	mV		70%
817.5484	825.8065	834.0645	mV		160%
867.0968	875.8553	884.6139	mV		130%
916.6452	925.9042	935.1632	mV	- 25	100%
966.1935	975.9531	985.7126	mV	1 1	70%
1015.742	1026.002	1036.262	mV		160%
1065.29	1076.051	1086.811	mV		130%
1114.839	1126.1	1137.361	mV	- 30	100%
1164.387	1176.149	1187.91	mV	1 1	70%
1213.935	1226.197	1238.459	mV		160%
1263.484	1276.246	1289.009	mV	1	130%
1313.032	1326.295	1339.558	mV	- 35 -	100%
1362.581	1376.344	1390.108	mV	1 1	70%
1412.129	1426.393	1440.657	mV		160%
1461.677	1476.442	1491.206	mV	-1	130%
1511.226	1526.491	1541.756	mV	- 40	100%
1560.774	1576.54	1592.305	mV	-	70%

#### Table 2. SET[1 to 2] Pins Setting for QR\_TH and QRWIDTH



	V <sub>SET[3]_V</sub> = V <sub>I</sub>	$\frac{R1 \times R2}{R1 + R2}$		Force-Non- Zero VBOOT	TONSET_SA	DVID_SA (mV)
Min	Тур	Max	Unit			
24.77419	25.02444	25.27468	mV			15
74.32258	75.07331	75.82405	mV		0.6	30
123.871	125.1222	126.3734	mV		0.0	60
173.4194	175.1711	176.9228	mV			Disable
222.9677	225.2199	227.4721	mV			15
272.5161	275.2688	278.0215	mV		0.8	30
322.0645	325.3177	328.5709	mV		0.8	60
371.6129	375.3666	379.1202	mV	VBOOT for		Disable
421.1613	425.4154	429.6696	mV	hardware test		15
470.7097	475.4643	480.219	mV	]	4.4	30
520.2581	525.5132	530.7683	mV	]	1.1	60
569.8065	575.5621	581.3177	mV	1		Disable
619.3548	625.6109	631.8671	mV	1 [		15
668.9032	675.6598	682.4164	mV	1	0.4	30
718.4516	725.7087	732.9658	mV	1	0.4	60
768	775.7576	783.5152	mV	1		Disable
817.5484	825.8065	834.0645	mV			15
867.0968	875.8553	884.6139	mV	1	0.0	30
916.6452	925.9042	935.1632	mV	1	0.6	60
966.1935	975.9531	985.7126	mV	1		Disable
1015.742	1026.002	1036.262	mV	1 [		15
1065.29	1076.051	1086.811	mV	1	0.0	30
1114.839	1126.1	1137.361	mV	]	0.8	60
1164.387	1176.149	1187.91	mV	INTEL		Disable
1213.935	1226.197	1238.459	mV	VBOOT		15
1263.484	1276.246	1289.009	mV	] [	1.1	30
1313.032	1326.295	1339.558	mV	] [		60
1362.581	1376.344	1390.108	mV	] [		Disable
1412.129	1426.393	1440.657	mV	1		15
1461.677	1476.442	1491.206	mV	]	<b>a</b> :	30
1511.226	1526.491	1541.756	mV	]	0.4	60
1560.774	1576.54	1592.305	mV	] [		Disable

#### Table 3. SET3 Pin Setting for Force-Non-Zero-VBOOT, $k_{\text{TON}},$ and DVID\_TH

For better efficiency of the given load range, the maximum switching frequency is suggested to be :

 $\frac{VID1 + \frac{IccTDC}{N} \cdot \left(DCR + \frac{R_{ON\_LS,max}}{n_{LS}} - N \cdot R_{LL}\right)}{\left[V_{IN(MAX)} + \frac{IccTDC}{N} \cdot \left(\frac{R_{ON\_LS,max}}{n_{LS}} - \frac{R_{ON\_HS,max}}{n_{HS}}\right)\right] \cdot \left(T_{ON} - T_{D} + T_{ON,VAR}\right) + \frac{IccTDC}{N} \cdot \left(\frac{R_{ON\_LS,max}}{n_{LS}}\right) \cdot T_{D} \cdot$ 

where  $F_{SW(MAX)}$  is the maximum switching frequency, VID1 is the typical VID of application,  $V_{IN(MAX)}$  is the maximum application input voltage, IccTDC is the thermal design current of application, N is the phase number. The  $R_{ON\_HS,max}$  is the maximum equivalent high-side  $R_{DS(ON)}$ , and  $n_{HS}$  is the number of high-side MOSFETs;  $R_{ON\_LS,max}$ is the maximum equivalent low-side  $R_{DS(ON)}$ , and  $n_{LS}$  is the number of low-side MOSFETs.  $T_D$  is the summation of the high-side MOSFET delay time and the rising time,  $T_{ON, VAR}$  is the  $T_{ON}$  variation value. DCR is the inductor DCR, and  $R_{LL}$  is the loadline setting. In addition, Richtek provides a Microsoft Excel-based spreadsheet to help design the  $R_{TON}$  for the RT3602AC.

When load increases, on-time keeps constant. The offtime width will be reduced so that loading can load more power from input terminal to regulate output voltage. Hence, the loading current usually increases in case the switching frequency also increases. Higher switching frequency operation can reduce power components' size and PCB space, trading off the whole efficiency since switching related loss increases, vice versa.

#### **Current Sense**

In the RT3602AC, the current signal is used for load-line setting and over-current protection (OCP). The inductor current sense method adopts the lossless current sensing for allowing high efficiency as illustrated in Figure 10. If RC network time constant matches inductor time constant  $L_X/DCR_X$ , an expected load transient waveform can be designed. If  $R_XC_X$  network time constant is larger than inductor time constant  $L_X/DCR_X$ , vcore waveform has a sluggish droop during load transient. If  $R_XC_X$  network is smaller than inductor time constant  $L_X/DCR_X$ , a worst  $V_{CORE}$  waveform will sag to create an undershooting to fail the specification.  $R_X$  is highly recommended as two 0603 size resistors in series to enhance the lout reporting accuracy.  $C_X$  is suggested X7R type for the application.

Figure 11 shows the variety  $R_X C_X$  constant corresponding to the output waveforms.



### Figure 10. Lossless Current Sense Method for Single Phase



Expected load transient waveform







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For dual phase current sense is demonstrated as Figure 12. It is similar to single phase method and it also can be extended to N phase application. In the RT3602AC design, the resistance of  $R_{CS}$  is equal to 2.15k $\Omega$ .



Figure 12. Lossless Current Sense Method for Dual Phase

#### **Thermal Compensation for Current Sense**

Since the copper wire of inductor has a positive temperature coefficient. And hence, temperature compensation is necessary for the lossless inductor current sense. For single phase thermal compensation, Figure 13. shows a not only simple but also effective way to compensate temperature variation. An NTC thermistor is put in the current sensing network and it can be used to compensate DCR variation due to temperature is changed.



The current sense network equation is as follows :

$$\Delta V_{IMON} = V_{IMON} - V_{REF} = \frac{I_{LX} \times DCR \times \frac{R_{S} + (R_{P} / / R_{NTC})}{R_{X} + (R_{S} + R_{P} / / R_{NTC})} \times R_{IMON}$$

Usually, R<sub>P</sub> is set equal to R<sub>NTC</sub> ( $25^{\circ}$ C). R<sub>S</sub> is selected to linearize the NTC's temperature characteristic. For a given NTC, design is to get R<sub>X</sub> and R<sub>S</sub> to compensate the temperature variation of the sense resistor.

Let

 $R_{EQU} = R_S + (R_P / / R_{NTC})$ 

According to current sense network, the corresponding equation is represented as follows :

$$\frac{L_X}{DCR} = C_X \times \frac{R_{EQU} \times R_X}{R_{EQU} + R_X}$$

Next, let

$$m = \frac{L_X}{DCR \times C_X}$$

Then

$$m \times \left(R_{X} + R_{S} + \frac{R_{NTC} \times R_{P}}{R_{NTC} + R_{P}}\right) = R_{X} \times \left(R_{S} + \frac{R_{NTC} \times R_{P}}{R_{NTC} + R_{P}}\right)$$

Step1 : Given the two system temperature  $T_{\text{R}}$  and  $T_{\text{H}}$  at which are compensated.

Step2 : Two equations can be listed as

$$m(T_R) \times \left( R_X + R_S + \frac{R_{NTC}(T_R) \times R_P}{R_{NTC}(T_R) + R_P} \right) = R_X \times \left( R_S + \frac{R_{NTC}(T_R) \times R_P}{R_{NTC}(T_R) + R_P} \right)$$

$$m(T_{H}) \times \left(R_{X} + R_{S} + \frac{R_{NTC}(T_{H}) \times R_{P}}{R_{NTC}(T_{H}) + R_{P}}\right) = R_{X} \times \left(R_{S} + \frac{R_{NTC}(T_{H}) \times R_{P}}{R_{NTC}(T_{H}) + R_{P}}\right)$$

Step3 : Usually  $R_P$  is set to equal to  $R_{NTC}$  ( $T_R$ ). And hence, there are two equations and two unknowns,  $R_X$  and  $R_S$  can be found out.

Above thermal compensation method needs a NTC resistor in each phase. In order to reduce the NTC amount for multiphase application, another thermal compensation method is presented. This method can be applied to multi-phase application and it only needs one NTC resistor. So, the NTC resistor cost can be saved by using this method. Figure 14 shows the thermal compensation method for dual phase.



Figure 14. Thermal Compensation Method for **Dual Phase** 

The current sense network equation is as follows :

 $V_{IMON} - V_{ref} = \frac{\sum_{i=1}^{Z} I_{LX} \times DCR}{R_{CS}} \times \{R_{IMON1} + [R_{IMON2} / / (R_{IMON3} + R_{NTC})]\}$ 

Please note that  $V_{IMON}$  is equal to 1V for single phase application and  $V_{IMON}$  is equal to 1.4V for dual phase application under ICCMAX condition.

A resistor network with NTC thermistor compensation connecting between IMON pin and VREF pin is used to compensate the positive temperature coefficient of inductor DC. The design flow is as follows :

Step 1: Given the three temperature  $T_L$ ,  $T_R$  and  $T_H$ , at which are compensated.

Step 2 : Three equations can be listed as

$$\frac{DCR(T_L)}{R_{CS}} = \sum_{i=1}^{2} I_{Li} \times R_{IMON}(T_L) = 0.4$$
$$\frac{DCR(T_R)}{R_{CS}} = \sum_{i=1}^{2} I_{Li} \times R_{IMON}(T_R) = 0.4$$
$$\frac{DCR(T_H)}{R_{CS}} = \sum_{i=1}^{2} I_{Li} \times R_{IMON}(T_H) = 0.4$$

Where :

(1) The relationship between DCR and temperature is as follows :

 $DCR(T) = DCR(25^{\circ}C) \times [1+0.00393(T-25)]$ 

$$K_{TH} = \frac{0.4}{\frac{DCR(T_H)}{R_{CS}} \times I_{CCMAX}}$$

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(2) RIMON (T) is the equivalent resistor of the resistor network with a NTC thermistor

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$$R_{IMON}(T) = R_{IMON1} + \{R_{IMON2} / / [R_{IMON3} + R_{NTC}(T)]\}$$

And the relationship between NTC and temperature is as follows :

$$R_{NTC}(T) = R_{NTC}(25^{\circ}C) \times e^{\beta(\frac{1}{T+273} - \frac{1}{298})}$$

 $\beta$  is in the NTC thermistor datasheet.

Step 3: Three equation and three unknowns, RIMON1, RIMON2 and RIMON3 can be calculated out unique solution.

 $R_{IMON1} = K_{TR} - \frac{R_{IMON2} \times (R_{NTCTR} + R_{IMON3})}{R_{IMON2} + R_{NTCTR} + R_{IMON3}}$ 

 $R_{IMON2} = \sqrt{[K_{R3}^2 + K_{R3}(R_{NTCTL} + R_{NTCTR}) + R_{NTCTL}R_{NTCTR}]\alpha_{TL}}$ 

 $R_{IMON3} = -R_{IMON2} + K_{R3}$ Where :

$$\alpha_{TH} = \frac{K_{TH} - K_{TR}}{R_{NTCTH} - R_{NTCTR}}$$

 $\alpha_{TL} = \frac{K_{TL} - K_{TR}}{R_{NTCTL} - R_{NTCTR}}$ 

$$K_{R3} = \frac{(\alpha_{TH}/\alpha_{TL})R_{NTCTH} - R_{NTCTL}}{1 - (\alpha_{TH}/\alpha_{TL})}$$

$$K_{TL} = \frac{0.4}{\frac{DCR(T_L)}{R_{CS}} \times I_{CCMAX}}$$

$$K_{TR} = \frac{0.4}{\frac{DCR(T_R)}{R_{CS}} \times I_{CCMAX}}$$

$$K_{TH} = \frac{0.4}{\frac{DCR(T_H)}{R_{CS}} \times I_{CCMAX}}$$

#### **Current Monitor, IMON**

For each VR rail, the RT3602AC includes a current monitor (IMON) function which can be used to detect over-current protection and maximum processor current ICCMAX, and also sets a part of current gain in the load-line setting. It produces an analog voltage proportional to output current between the IMON and VREF pins.

#### Load-Line (Droop) Setting

The G-NAVP<sup>TM</sup> topology can set load-line (droop) via the current loop and voltage loop, the load-line is a slope between load current  $I_{CC}$  and output voltage Vsen as shown in Figure 15. Figure 16 shows the voltage control and current loop for AUXI and SA rails. By using both loops, the load-line (droop) can be set easily. The load-line set equation for AUXI and SA is :



 $R_{LL} \times I_{CC}$ 



Figure 15. Load-Line (Droop)

Figure 16. Voltage Loop and Current Loop for AUXI and SA Rails

Current Loop

Figure 17 shows the voltage control and current loop for MAIN rail. By using both loops, the load-line (droop) can be set easily. The load-line set equation for MAIN is :

$$R_{LL} = \frac{A_{I}}{A_{V}} = \frac{\frac{k_{i}}{2} \times \frac{DCR}{R_{CS}} \times R_{IMON}}{\frac{R_{2}}{R_{1}}}$$

Where R<sub>CS</sub> =  $2.15k\Omega$ 





#### **Compensator Design**

The compensator of the RT3602AC doesn't need a complex type II or type III compensator to optimize control loop performance. It can adopt a simple type I compensator (one pole, one zero) in the G-NAVP<sup>TM</sup> topology to achieve constant output impedance design for Intel IMVP8 ACLL specification. The one pole one zero compensator is shown as Figure 18. The transfer function of compensator should be design as following transfer function to achieve constant output impedance, i.e. Zo(s) = load-line slope in the entire frequency range :

$$G_{CON}(S) \approx \frac{A_l}{R_{LL}} \frac{1 + \frac{S}{\omega \times f_{SW}}}{1 + \frac{S}{\omega_{ESR}}}$$

where A<sub>I</sub> is current loop gain, R<sub>LL</sub> is load-line,  $f_{SW}$  is switching frequency and  $\omega_{ESR}$  is a pole that should be located at 1/(C<sub>OUT</sub> x ESR). Then, the C1 and C2 should be designed as follows :

$$C1 = \frac{1}{R1 \times \pi \times f_{SW}} \qquad C2 = \frac{C_{OUT} \times ESR}{R2}$$

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IMONA

RIMON

ISENN

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Figure 18. Type I compensator

#### **Differential Remote Sense Setting**

The VR provides differential remote-sense inputs to eliminate the effects of voltage drops along the PC board traces, CPU internal power routes and socket contacts for MAIN and AUXI rails. The CPU contains on-die sense pins,  $V_{CC\_SENSE}$  and  $V_{SS\_SENSE}$ . Connect RGND to  $V_{SS\_SENSE}$  and connect FB to  $V_{CC\_SENSE}$  with a resistor to build the negative input path of the error amplifier as shown in Figure 19. The  $V_{DAC}$  and the precision voltage reference are referred to RGND for accurate remote sensing.



Figure 19. Remote Sensing Circuit

#### Maximum Processor Current Setting, IMAX

The maximum processor current IMAX for each VR rail can be set by TSEN\_Main and TSEN\_AUXI pins. Each VR IMAX register is set by an external voltage divider with the multi-function mechanism. Table 4 and Table 5 show the each VR IMAX setting on TSEN\_Main and TSEN\_ AUXI pins.

#### System Input Power Monitor, PSYS

The RT3602AC provides PSYS function to monitor total platform system power, and the obtained information will be provided directly to the CPU via the SVID interface. The PSYS function can be described as in Figure 20. When the maximum PSYS voltage  $V_{PSYS}$  =3.2V, the RT3602AC will generate an 8-bit code, FF, which will be stored in the 1Bh register. To choose the resistor value R, for example, if the maximum current from the PSYS "Meter" I = 320µA in conjunction with  $V_{PSYS}$  = 3.2V and R =  $V_{PSYS}/I$  =10k $\Omega$  can be obtained.



Figure 20. PSYS Function Block Diagram


$V_{\text{TSEN}AUXI} = V_{\text{REF}} \times \frac{\text{R1} \times \text{R2}}{\text{R1} + \text{R2}}$				ICCMAX_MAIN (A)				SA_0LL
Min	Typical	Мах	Unit	1-Phase	1-Phase POCP	2-Phase	2-Phase POCP	
49.5484	50.0489	50.5494	mV	16	48	29	43.5	Disable
148.645	150.147	151.648	mV	10	40	29	45.5	Enable
247.742	250.244	252.747	mV	18	54	33	49.5	Disable
346.839	350.342	353.846	mV	10	54		49.5	Enable
445.935	450.44	454.944	mV	20	60	37	55.5	Disable
545.032	550.538	556.043	mV	20	00	57	55.5	Enable
644.129	650.635	657.142	mV	01	62	40	60	Disable
743.226	750.733	758.24	mV	21	63	40	60	Enable
842.323	850.831	859.339	mV	22	66	44	66	Disable
941.419	950.929	960.438	mV		00	44	00	Enable
1040.52	1051.03	1061.54	mV	22	60	46	46 69	Disable
1139.61	1151.12	1162.64	mV	23	69	9 46		Enable
1238.71	1251.22	1263.73	mV		40	70	Disable	
1337.81	1351.32	1364.83	mV	24	72	48	72	Enable
1436.9	1451.42	1465.93	mV	0.5	75 40	40	72.5	Disable
1536	1551.52	1567.03	mV	25	75	49	73.5	Enable
1635.1	1651.61	1668.13	mV	26	50	50	50	Disable
1734.19	1751.71	1769.23	mV	26	52	50	50	Enable
1833.29	1851.81	1870.33	mV	07	E A	E4 E2	52	Disable
1932.39	1951.91	1971.43	mV	27	54	52	52	Enable
2031.48	2052	2072.52	mV	28	56	50	52	Disable
2130.58	2152.1	2173.62	mV	20	56	53	53	Enable
2229.68	2252.2	2274.72	mV	20	59	55	55	Disable
2328.77	2352.3	2375.82	mV	29	58	55		Enable
2427.87	2452.39	2476.92	mV	20	00			Disable
2526.97	2552.49	2578.02	mV	30	60	57	57	Enable
2626.06	2652.59	2679.12	mV	21	60	62 59	50	Disable
2725.16	2752.69	2780.22	mV	31	62		59	Enable
2824.26	2852.79	2881.31	mV	22	66			Disable
2923.35	2952.88	2982.41	mV	33	66	61	61	Enable
3022.45	3052.98	3083.51	mV	05	70	64	64	Disable
3121.55	3153.08	3184.61	mV	35	70	64	64	Enable

Table 4. TSEN\_AUXI Setting for IMAX\_MAIN and zero load-line



$V_{\text{TSEN}}$ = $V_{\text{REF}} \times \frac{\text{R1} \times \text{R2}}{\text{R1} + \text{R2}}$			IMAX_AUXI (A)		IMAX_SA (A)		
Min	Typical	Max	Unit	IMAX	POCP	IMAX	POCP
49.5484	50.0489	50.5494	mV			3	18
148.645	150.147	151.648	mV			4	24
247.742	250.244	252.747	mV	- 16	48	5	30
346.839	350.342	353.846	mV			6	36
445.935	450.44	454.944	mV			3	18
545.032	550.538	556.043	mV	10	<b>F</b> 4	4	24
644.129	650.635	657.142	mV	- 18	54	5	30
743.226	750.733	758.24	mV	1		6	36
842.323	850.831	859.339	mV			3	18
941.419	950.929	960.438	mV		60	4	24
1040.52	1051.03	1061.54	mV	20		5	30
1139.61	1151.12	1162.64	mV			6	36
1238.71	1251.22	1263.73	mV		66	3	18
1337.81	1351.32	1364.83	mV			4	24
1436.9	1451.42	1465.93	mV	22		5	30
1536	1551.52	1567.03	mV			6	36
1635.1	1651.61	1668.13	mV		24 48	3	18
1734.19	1751.71	1769.23	mV			4	24
1833.29	1851.81	1870.33	mV	- 24		5	30
1932.39	1951.91	1971.43	mV			6	36
2031.48	2052	2072.52	mV			3	18
2130.58	2152.1	2173.62	mV		52	4	24
2229.68	2252.2	2274.72	mV	- 26		5	30
2328.77	2352.3	2375.82	mV			6	36
2427.87	2452.39	2476.92	mV			3	18
2526.97	2552.49	2578.02	mV		29 58	4	24
2626.06	2652.59	2679.12	mV	- 29		5	30
2725.16	2752.69	2780.22	mV	1		6	36
2824.26	2852.79	2881.31	mV			3	18
2923.35	2952.88	2982.41	mV	1		4	24
3022.45	3052.98	3083.51	mV	- 35	70	5	30
3121.55	3153.08	3184.61	mV	1		6	36

Table 5. TSEN\_MAIN Setting for IMAX\_AUXI and IMAX\_SA

#### **Dynamic VID (DVID) Compensation**

When VID transition event occurs, a charge current will be generated in the loop to cause DVID performance is deteriorated by this induced charge current, the phenomenon is called droop effect. The droop effect is shown in Figure 21. When VID up transition occurs, the output capacitor will be charged by inductor current. Since current signal is sensed in inductor, an induced charge current will appear in control loop. The induced charge current will produce a voltage drop in R1 to cause output voltage to have a droop effect. Due to this, VID transition performance will be deteriorated.

The RT3602AC provides a DVID compensation function. By the DVID compensation to cancel the real induced charge current signal and the virtual charge current signal is defined in Figure 22. Figure 23 shows the operation of cancelling droop effect. A virtual charge current signal is established first and then VID signal plus virtual charge current signal to be generated on the FB pin. Hence, an induced charge current signal flows to R1 and is cancelled to reduce droop effect.

#### Charge current VIN C Q1 Coz C<sub>O1</sub> 02 Gate Driver Induced charge Output voltage current signal C1 R2 CCRCOT ╢ $\wedge \wedge$ COMP VINC R1 VID ĒA IDROOF VID

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VID Transition



Figure 22. Definition of Virtual Charge Current Signal



Figure 23. DVID Compensation

Table 3 and Table 7 show the each VR DVID threshold setting on TSEN\_Main and TSEN\_AUXI pins. The each VR DVID width is equal to  $2\mu$ s. For example, VR IMAXs are 31A, 6A and 35A for MAIN rail, SA rail and AUXI rail, respectively. And DIVDTHs are all set as 15mV for each rail. The V<sub>TSEN\_Main</sub> and V<sub>TSEN\_AUXI</sub> need to be set as 3.15V and 2.65V, respectively. Please note that a high accuracy resistor is needed for this setting, <1% error tolerance is recommended.

#### **Ramp Compensation**

The G-NAVP<sup>TM</sup> topology is one type of ripple based control that has fast transient response and can lower BOM cost. However, ripple based control usually has no good noise immunity. The RT3602AC provides the ramp compensation to increase noise immunity and reduce jitter at the switching node. Figure 24 shows the ramp compensation.



Figure 24. Ramp Compensation

#### Quick Response (QR) Mechanism

When the transient load step-up becomes quite large, it is difficult for loop response to meet the energy transfer. Hence, that output voltage generate undershoot to fail specification. The RT3602AC has Quick Response (QR) mechanism being able to improve this issue. It adopts a nonlinear control mechanism which can disable interleaving function and simultaneously turn on all UGATE one pulse at instantaneous step-up transient load to restrain the output voltage drooping. Figure 25 shows the QR behavior.



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Figure 25. Quick Response Mechanism

The output voltage signal behavior needs to be detected so that QR mechanism can be trigged. The output voltage signal is via a remote sense line to connect at the VSEN pin which is shown in Figure 26. The QR mechanism needs to set QR width and QR threshold. Both definitions are shown in Figure 25. A proper QR mechanism set can meet different applications. The SET1 and SET2 pins can set QR threshold and QR width by internal current source  $80\mu$ A with multi-function pin setting mechanism for MAIN and AUXI VR rails. Table 2 shows the QR\_TH and QR\_WIDTH for MAIN and AXUI VR rails on the SET[1 to 2] pins.



Figure 26. Simplified QR Trigger schematic



$V_{\text{SET[1 to 2]_l}} = 80\mu \times \frac{\text{R2}}{\text{R1+R2}}$			TONSET_X	AI_X		ANTIOVS_X	
Min	Тур	Max	Unit		AUXI	MAIN	
60.07331	75.07331	90.07331	mV			4	Disable
160.1711	175.1711	190.1711	mV	0.6	20	1	Enable
260.2688	275.2688	290.2688	mV	0.0	80	2	Disable
360.3666	375.3666	390.3666	mV		80	2	Enable
460.4643	475.4643	490.4643	mV		20 80	1	Disable
560.5621	575.5621	590.5621	mV	0.0			Enable
660.6598	675.6598	690.6598	mV	0.8		2	Disable
760.7576	775.7576	790.7576	mV		80	2	Enable
860.8553	875.8553	890.8553	mV		20 80	1	Disable
960.9531	975.9531	990.9531	mV	1.1			Enable
1061.051	1076.051	1091.051	mV	1.1			Disable
1161.149	1176.149	1191.149	mV				Enable
1261.246	1276.246	1291.246	mV		20	1	Disable
1361.344	1376.344	1391.344	mV	0.4		1	Enable
1461.442	1476.442	1491.442	mV	0.4		2	Disable
1561.54	1576.54	1591.54	mV		80	۷	Enable

Table 6. SET[1 to 2] Pins	s Setting for k <sub>TON</sub> , ki, and ANTIOVS
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For example, 35mV QR threshold and 1.3 x TON QR width are set. According to Table 2, the set voltage should be between 1.261V and 1.291V. Please note that a high accuracy resistor is needed for this setting accuracy, <1% error tolerance is recommended.

#### Zero Load-Line Setting and Anti-overshoot function

The TSEN\_AUXI can be enabled/disabled zero load-line function for SA rail. The SET1 and SET2 pins can be enabled/disabled anti-overshoot function for MAIN and AUXI rails.

When DVID slew rate increases, loop response is difficult to meet energy transfer so that output voltage generates overshoot to fail specification. The RT3602AC has antiovershoot function being able to help improve this issue. The VR will turn off low-side MOSFET when output voltage ramps up to the target VID (ALERT signal be pulled low). This function also can improve the overshoot during the load transient condition. When anti-overshoot function is triggered, the UGATE and LGATE signal will be masked to reduce the overshoot amplitude.

	V <sub>SET3_</sub> I = 8	$0\mu \times \frac{R1 \times R2}{R1 + R2}$	DVIDTH_MAIN (mV)	DVIDTH_AUXI (mV)	
Min	Тур	Max	Unit		
60.07331	75.07331	90.07331	mV		15
160.1711	175.1711	190.1711	mV	- 15	30
260.2688	275.2688	290.2688	mV	15	60
360.3666	375.3666	390.3666	mV		Disable
460.4643	475.4643	490.4643	mV	20	15
560.5621	575.5621	590.5621	mV		30
660.6598	675.6598	690.6598	mV	- 30	60
760.7576	775.7576	790.7576	mV		Disable
860.8553	875.8553	890.8553	mV		15
960.9531	975.9531	990.9531	mV	60	30
1061.051	1076.051	1091.051	mV	60	60
1161.149	1176.149	1191.149	mV		Disable
1261.246	1276.246	1291.246	mV		15
1361.344	1376.344	1391.344	mV	Dischla	30
1461.442	1476.442	1491.442	mV	- Disable	60
1561.54	1576.54	1591.54	mV		Disable

#### Table 7. SET3 Pin Setting for DVIDTH

#### **Over-Current Protection**

The RT3602AC has dual OCP mechanism. One is named SUM-OCP, the other is called SPIKE-OCP. The over current protection (OCP) forces high-side MOSFET and low-side MOSFET off by shutting down internal PWM logic drivers. The RT3602AC provides SUM-OCP which is 160% of IMON 04. IMON 04 is the current that makes (VIMON - $V_{REF}$ ) = 0.4V. When output current is higher than the SUM-OCP threshold, SUM-OCP is latched with a 40µs delay time to prevent false trigger. Besides, the SUM-OCP function is masked when dynamic VID transient occurs and after dynamic VID transition, SUM-OCP is masked for 80µs. The other one is SPIKE-OCP which should trip when the output current exceeds SPIKE\_OCP threshold during first DVID. SPIKE OCP threshold is dependent on IMAX level as shown in Table 4 and Table 5. When output current is higher than the SPIKE-OCP threshold, SPIKE-OCP is latched with a 1µs delay time to prevent false trigger.

#### **Output Over-Voltage Protection**

An OVP condition is detected when the VSEN pin is 350mV more than VID. When OVP is detected, the high-side gate voltage UGATEx is pulled low and the low-side gate voltage LGATEx is pulled high. OVP is latched with a  $0.5\mu$ s delay- to prevent false trigger.

#### **Negative Voltage Protection**

Since the OVP latch continuously turns on all low-side MOSFETs of the VR, the VR will suffer negative output voltage. When the VSEN detects a voltage below -0.07V after triggering OVP, the VR triggers NVP to turn off all low-side MOSFETs of the VR while the high-side MOSFETs remain off. After triggering NVP, if the output voltage rises above 0V, the OVP latch restarts to turn on all low-side MOSFETs. Therefore, the output voltage may bounce between 0V and -0.07V due to OVP latch and NVP triggering. The NVP function will be active only after OVP is triggered.

#### **Under-Voltage Protection**

When the VSEN pin voltage is 350mV less than VID, UVP will be latched. When UVP latched, the both UGATEx and LGATEx are pulled low. A  $3\mu$ s delay is used in UVP

detection circuit to prevent false trigger. Besides, the UVP function is masked when dynamic VID transient occurs and after dynamic VID transition, UVP is masked for 80µs.

#### Design Step :

The RT3602AC Excel based design tool is available. Users can contact your Richtek representative to get the spreadsheet. Three main design procedures of the RT3602AC design, first step is loop design, second step is pin setting design, and the last step is protection settings. The following design example is to explain the RT3602AC design procedure :

#### AUXI VR

	V <sub>AUXI</sub> Specification
Input Voltage	19V
No. of Phase	1
Normal VID	1.35V
ICCMAX	35
ICC-Dyn	28
Load-Line	2.1mΩ
Fast Slew Rate	37.5mV/μs
MAX Switching Frequency	700kHz

The output filter requirements of VRTB specification are as follows :

Output Inductor :  $220nH/0.875m\Omega$ 

Output Ceramic Capacitor: 47µF (6pcs)

Output Ceramic Capacitor:10µF (9pcs)

Loop Design :

- On time setting: Using the specification, then can get that  $T_{\text{ON}}$  is 108ns.

The  $k_{\text{TON}}$  parameter can be calculated after the on-time is decided.

$$T_{ON} = \frac{1.2\mu \times V_{DAC}}{k_{TON} \times (V_{IN} - V_{DAC})} + 15n$$

Choosing the nearest on-time setting  $k_{TON} = 1.1$ 



• Current sensor adopts lossless RC filter to sense current signal in DCR. For getting an expected load transient waveform  $R_XC_X$  time constant needs to match  $L_X/DCR_X$ .  $C_X = 0.47\mu$ F,  $R_{NTC} = 10$ k $\Omega$  and  $R_P = 10$ k $\Omega$  are set, then

 $R_{EQU} = R_S + (R_P //R_{NTC})$ 

$$\frac{L_X}{DCR} = C_X \times \frac{R_{EQU} \times R_X}{R_{EQU} + R_X}$$

By using the design tool,  $R_S$  and  $R_X$  can be determined, are equal to 220 $\Omega$  and 590 $\Omega$ , respectively.

• IMON resistor network design :

$$R_{IMON} = \frac{\Delta V_{IMON} \times 2.15k}{ICCMAX \times DCR \times \frac{R_{EQU}}{R_X + R_{EQU}}} = 31.25k\Omega$$

• Load-line design :  $2.1m\Omega$  droop is requirement, because DCR and ki are decided to  $0.875m\Omega$  and 20, respectively. The voltage loop Av gain is also can be determined by following equation :

$$\mathsf{R}_{\mathsf{LL}} = \frac{\mathsf{A}_{\mathsf{I}}}{\mathsf{A}_{\mathsf{V}}} = \frac{\frac{\mathsf{k}_{\mathsf{i}}}{2} \times \mathsf{DCR}}{\frac{\mathsf{R}_{\mathsf{2}}}{\mathsf{R}_{\mathsf{1}}}}$$

 $R_1$  = 10k $\Omega$  is usually decided and here R2 is chosen to 37.4k $\Omega.$ 

• Typical compensator design can use the following equations to design  $C_1$  and  $C_2$  values

$$C_{1} = \frac{1}{R_{1} \times \pi \times F_{SW}} \approx 45.5 \text{pF}$$
$$C_{2} = \frac{C_{OUT} \times ESR}{R_{2}} \approx 33 \text{pF}$$

For Intel platform, in order to induce the band width to enhance transient performance to meet Intel's criterion, the zero location can be designed close to 1/10 of the switching frequency or less than the 1/10 of switching frequency.

#### SA VR

	V <sub>SA</sub> Specification
Input Voltage	19V
No. of Phase	1
Normal VID	1.05V
ICCMAX	6
ICC-Dyn	3
Load-Line	10.3mΩ
Fast Slew Rate	37.5mV/μs
MAX Switching Frequency	800kHz

The output filter requirements of VRTB specification are as follows :

Output Inductor: 820nH/6.7mΩ

Output Ceramic Capacitor: 47µF (4pcs)

Output Ceramic Capacitor:10µF (8pcs)

Loop Design :

- On time setting : Using the specification, then can get that  $T_{\text{ON}}$  is 96ns.

The  $k_{\text{TON}}$  parameter can be calculated after the on-time is decided.

$$T_{ON} = \frac{1.2\mu \times V_{DAC}}{k_{TON} \times (V_{IN} - V_{DAC})} + 15n$$

Choosing the nearest on-time setting  $k_{TON} = 1.1$ 

Current sensor adopts lossless RC filter to sense current signal in DCR. For getting an expected load transient waveform R<sub>X</sub>C<sub>X</sub> time constant needs to match L<sub>X</sub>/DCR<sub>X</sub>. C<sub>X</sub> = 0.47 $\mu$ F, R<sub>NTC</sub> = 4.7k $\Omega$  and Rp = 4.7k $\Omega$  are set, then

$$R_{EQU} = R_S + (R_P / / R_{NTC})$$

$$\frac{L_X}{DCR} = C_X \times \frac{R_{EQU} \times R_X}{R_{EQU} + R_X}$$

By using the design tool,  $R_S$  and  $R_X$  can be determined, are equal to 165 $\Omega$  and 280 $\Omega$ , respectively.

• IMON resistor network design :

 $R_{IMON} = \frac{\Delta V_{IMON} \times 2.15k}{ICCMAX \times DCR \times \frac{R_{EQU}}{R_X + R_{EQU}}} = 23.79 k\Omega$ 

 Load-line design : 10.3mΩ droop is requirement, because DCR and ki are decided to 6.7mΩ and 20, respectively. The voltage loop Av gain is also can be determined by following equation :

$$R_{LL} = \frac{A_{I}}{A_{V}} = \frac{\frac{k_{i}}{2} \times DCR}{\frac{R_{2}}{R_{1}}}$$

 $R_1$  = 10k $\Omega$  is usually decided and here R2 is chosen to 58.5k $\Omega.$ 

Typical compensator design can use the following equations to design  $C_1$  and  $C_2$  values

$$C_{1} = \frac{1}{R_{1} \times \pi \times F_{SW}} \approx 45.5 \text{pF}$$
$$C_{2} = \frac{C_{OUT} \times ESR}{R_{2}} \approx 56 \text{pF}$$

For Intel platform, in order to induce the band width to enhance transient performance to meet Intel's criterion, the zero location can be designed close to 1/10 of the switching frequency or less than the 1/10 of switching frequency.

#### MAIN VR

	V <sub>MAIN</sub> Specification
Input Voltage	19V
No. of Phase	1
Normal VID	1.35V
ICCMAX	31
ICC-Dyn	28
Load-Line	3.1mΩ
Fast Slew Rate	37.5mV/μs
MAX Switching Frequency	700kHz

The output filter requirements of VRTB specification are as follows :

Output Inductor: 220nH/0.875m  $\!\Omega$ 

Output Bulk Capacitor:  $330\mu$ F/2V.4.5m $\Omega$  (1pcs)

Output Ceramic Capacitor: 47µF (6pcs)

Output Ceramic Capacitor:  $22\mu F$  (7pcs)

Output Ceramic Capacitor:10µF (2pcs)

Loop Design :

• On time setting: Using the specification, then can get that T<sub>ON</sub> parameter can be calculated after the on-time is decided.

$$T_{ON} = \frac{1.2 \mu \times V_{DAC}}{k_{TON} \times (V_{IN} - V_{DAC})} + 15n$$

Choosing the nearest on-time setting  $k_{TON} = 1.1$ 

• Current sensor adopts lossless RC filter to sense current signal in DCR. For getting an expected load transient waveform  $R_XC_X$  time constant needs to match  $L_X/DCR_X$ .  $C_X = 0.47\mu$ F is set, then

$$R_{X} = \frac{L_{X}}{1\mu F \times DCR_{X}} = 530\Omega$$

- IMON resistor network design :  $T_L = 25^{\circ}C$ ,  $T_R = 50^{\circ}C$ and  $T_H = 100^{\circ}C$  are decided, NTC thermistor =  $100k\Omega$ @ 25°C,  $\beta = 4485$  and ICCMAX = 31A.  $R_{IMON1} =$  $16.74k\Omega$ ,  $R_{IMON2} = 17.35k\Omega$  and  $R_{IMON3} = 9.16k\Omega$  can be decided. The  $R_{EQ}(25^{\circ}C) = 31.78k\Omega$ .
- Load-line design: 3.1mΩ droop is requirement, because DCR and ki are decided to 0.875mΩ and 2, respectively. The voltage loop Av gain is also can be determined by following equation :

$$R_{LL} = \frac{A_{I}}{A_{V}} = \frac{\frac{k_{i}}{2} \times \frac{DCR}{R_{CS}} \times R_{IMON}}{\frac{R_{2}}{R_{1}}}$$

 $R_{_1}$  = 10k $\Omega$  is usually decided and here R2 is chosen to 42.2k $\Omega.$ 

• Typical compensator design can use the following equations to design C<sub>1</sub> and C<sub>2</sub> values

$$C_1 = \frac{1}{R_1 \times \pi \times F_{SW}} \approx 45.5 pF$$

$$C_2 = \frac{C_{OUT} \times ESR}{R_2} \approx 55 pF$$

For intel platform, in order to induce the band width to enhance transient performance to meet intel's criterion, the zero location can be designed close to 1/10 of the switching frequency or less than the 1/10 of switching frequency.



Pin Setting Design :

SET1 resistor network design: From above designs, parameters of  $k_{TON\_AUXI}$  and  $k_{i\_AUXI}$  are 1.1 and 20, respectively. The AUXI\_QR\_TH is set to disable and AUXI\_QR\_Width is designed as 0.7 x T<sub>ON</sub>. And antiovershoot function is disabled for MAIN rail. By using the information, the two equation can be listed by using multi-function pin setting mechanism :

$$3.2 \times \frac{R_2}{R_1 + R_2} = 175.17 \text{mV}$$

$$80\mu \times \frac{R_1 \times R_2}{R_1 + R_2} = 975.9 \text{mV}$$

 $R_1 = 222.86 k\Omega$  and  $R_2 = 12.91 k\Omega$ .

• SET2 resistor network design : From above designs, parameters of  $k_{TON\_MAIN}$  and  $k_{i\_MAIN}$  are 1.1 and 2, respectively. The MAIN\_QR\_TH is set to 15mV and MAIN\_QR\_Width is designed as 0.7 x T<sub>ON</sub>. And antiovershoot function is enabled for AUXI rails. By using the information, the two equation can be listed by using multi-function pin setting mechanism :

$$3.2 \times \frac{R_2}{R_1 + R_2} = 575.56 \text{mV}$$
  
 $80 \mu \times \frac{R_1 \times R_2}{R_1 + R_2} = 1176.14 \text{mV}$ 

 $R_1 = 81.74 k\Omega$  and  $R_2 = 17.93 k\Omega$ .

SET3 resistor network design: From above designs, parameter of k<sub>TON\_SA</sub> is 1.1. The DVID thresholds are 60mV, 15mV, and 60mV for MAIN, AUXI, and SA rail. The force-non-zero VBOOT is setting as Intel VBOOT. By using the information, the two equation can be listed by using multi-function pin setting mechanism :

$$3.2 \times \frac{R_2}{R_1 + R_2} = 1326.3 \text{mV}$$
  
 $80 \mu \times \frac{R_1 \times R_2}{R_1 + R_2} = 875.86 \text{mV}$ 

$$R_1 = 26 4 k\Omega$$
 and  $R_2 = 18 7 k\Omega$ 

$$T_1 = 20.4KS2$$
 and  $T_2 = 10.7KS2$ .

• TSEN\_AUXI resistor network design : The ICCMAX of MAIN rail is designed as 31A. And zero load-line function for SA rail is disabled. By using the information, the equation can be shown as below :

$$3.2 \times \frac{R_2}{R_1 + R_2} = 2.65V$$

• TSEN\_MAIN resistor network design : The ICCMAXs are designed as 35A and 6A for AUXI and SA rail. By using the information, the equation can be listed by using multi-function pin setting mechanism :

$$3.2 \times \frac{R_2}{R_1 + R_2} = 3.15V$$

Protection Settings :

- OVP/UVP protections: When the VSEN pin voltage is 350mV higher than VID, the OVP will be latched. When the VSEN pin voltage is 350mV lower than VID, the UVP will be latched.
- TSEN and VR\_HOT design : Using the following equation to calculate related resistances for VR\_HOT setting.

$$V_{TSEN} = 80 \mu \times (R_3 / R_{NTC}) + (R_1 / R_2)$$

Choosing R<sub>1</sub> = 100k $\Omega$  and an NTC thermistor R<sub>NTC (25°C)</sub> = 100k $\Omega$  and its  $\beta$  = 4485. When temperature is 100°C, the R<sub>NTC (100°C)</sub> = 4.85k $\Omega$ . According to TSEN pins for multi-function mechanism, three equations can be got as following for AUXI VR rail :

$$V_{\text{TSEN AUXI(25^{\circ}C)}} = 80 \mu \times (R_3 / R_{\text{NTC } (25^{\circ}C)}) + (R_1 / R_2) = 1.624 V$$

 $V_{\text{TSEN AUXI(100^{\circ}C)}} = 80 \mu \times (R_3 / R_{\text{NTC (100^{\circ}C)}}) + (R_1 / R_2) = 1.092 V$ 

$$3.2 \times \frac{R_2}{R_1 + R_2} = 2.65V$$

 $R_1 = 8.94 k\Omega$ ,  $R_2 = 600.45 k\Omega$  and  $R3 = 5618.685 k\Omega$ .

Three equations can be got as following for MAIN VR rail :

 $V_{TSEN_{MAIN(25^{\circ}C)}} = 80 \mu \times (R_3 / R_{NTC(25^{\circ}C)}) + (R_1 / R_2) = 1.624 V$ 

 $V_{\text{TSEN}_{\text{MAIN}(100^{\circ}\text{C})}} = 80 \mu \times (R_3 //R_{\text{NTC}(100^{\circ}\text{C})}) + (R_1 //R_2) = 1.092 V$ 

$$3.2 \times \frac{R_2}{R_1 + R_2} = 3.15V$$

 $R_1$  = 8.94k $\Omega,$   $R_2$  = 63k $\Omega$  and R3 = 5618.685k $\Omega.$ 

#### **Thermal Considerations**

The junction temperature should never exceed the absolute maximum junction temperature  $T_{J(MAX)}$ , listed under Absolute Maximum Ratings, to avoid permanent damage to the device. The maximum allowable power dissipation depends on the thermal resistance of the IC package, the PCB layout, the rate of surrounding airflow, and the difference between the junction and ambient temperatures. The maximum power dissipation can be calculated using the following formula :

 $\mathsf{P}_{\mathsf{D}(\mathsf{MAX})} = (\mathsf{T}_{\mathsf{J}(\mathsf{MAX})} - \mathsf{T}_{\mathsf{A}}) / \theta_{\mathsf{J}\mathsf{A}}$ 

where  $T_{J(MAX)}$  is the maximum junction temperature,  $T_A$  is the ambient temperature, and  $\theta_{JA}$  is the junction-to-ambient thermal resistance.

For continuous operation, the maximum operating junction temperature indicated under Recommended Operating Conditions is 125°C. The junction-to-ambient thermal resistance,  $\theta_{JA}$ , is highly package dependent. For a WQFN-52L 6x6 package, the thermal resistance,  $\theta_{JA}$ , is 26.5°C/W on a standard JEDEC 51-7 high effective-thermal-conductivity four-layer test board. The maximum power dissipation at  $T_A = 25$ °C can be calculated as below :

 $\mathsf{P}_{\mathsf{D}(\mathsf{MAX})}$  = (125°C - 25°C) / (26.5°C/W) = 3.77W for a WQFN-52L 6x6 package

The maximum power dissipation depends on the operating ambient temperature for the fixed  $T_{J(MAX)}$  and the thermal resistance,  $\theta_{JA}$ . The derating curves in Figure 27 allows the designer to see the effect of rising ambient temperature on the maximum power dissipation.



Figure 27. Derating Curve of Maximum Power Dissipation

## **RT3602AC**



### **Outline Dimension**



Pin #1 ID and Tie Bar Mark Options

Note : The configuration of the Pin #1 identifier is optional, but must be located within the zone indicated.

Symbol	Dimensions I	n Millimeters	Dimensions In Inches		
Symbol	Min.	Max.	Min.	Max.	
A	0.700	0.800	0.028	0.031	
A1	0.000	0.050	0.000	0.002	
A3	0.175	0.250	0.007	0.010	
b	0.150	0.250	0.006	0.010	
D	5.950	6.050	0.234	0.238	
D2	4.650	4.750	0.183	0.187	
E	5.950	6.050	0.234	0.238	
E2	4.650	4.750	0.183	0.187	
е	0.400		0.0	16	
L	0.350	0.450	0.014	0.018	
L1	0.300	0.400	0.012	0.016	

W-Type 52L QFN 6x6 Package

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